



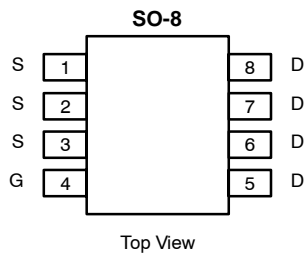
## N-Channel 30-V (D-S) MOSFET with Schottky Diode

### MOSFET PRODUCT SUMMARY

$V_{DS}$ (V)	$r_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)
30	0.018 @ $V_{GS} = 10$ V	9
	0.028 @ $V_{GS} = 4.5$ V	7.3

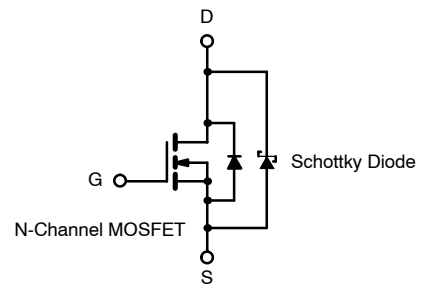
### SCHOTTKY PRODUCT SUMMARY

$V_{DS}$ (V)	$V_{SD}$ (V) Diode Forward Voltage	$I_F$ (A)
30	0.50 V @ 1.0 A	1.4



#### Ordering Information:

Si4812DY  
Si4812DY-T1 (with Tape and Reel)  
Si4812DY—E3 (Lead (Pb)-Free)  
Si4812DY-T1—E3 (Lead (Pb)-Free with Tape and Reel)



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter		Symbol	Limit		Unit
			10 sec	Steady State	
Drain-Source Voltage (MOSFET)		V <sub>DS</sub>	30		V
Reverse Voltage (Schottky)			30		
Gate-Source Voltage (MOSFET)		V <sub>GS</sub>	± 20		
Continuous Drain Current (T <sub>J</sub> = 150°C) (MOSFET) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	9	6.9	A
	T <sub>A</sub> = 70 °C		7.5	5.6	
Pulsed Drain Current (MOSFET)		I <sub>DM</sub>	50		
Continuous Source Current (MOSFET Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	2.1	1.2	
Average Foward Current (Schottky)		I <sub>F</sub>	1.4	0.8	
Pulsed Foward Current (Schottky)		I <sub>FM</sub>	30		
Maximum Power Dissipation (MOSFET) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.5	1.4	W
	T <sub>A</sub> = 70 °C		1.6	0.9	
Maximum Power Dissipation (Schottky) <sup>a, b</sup>	T <sub>A</sub> = 25 °C		2.0	1.2	
	T <sub>A</sub> = 70 °C		1.3	0.8	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	–55 to 150		°C

### THERMAL RESISTANCE RATINGS

Parameter	Device	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ( $t \leq 10$ sec) <sup>a</sup>	MOSFET	$R_{thJA}$	40	50	$^\circ\text{C/W}$
	Schottky		50	60	
Maximum Junction-to-Ambient ( $t = \text{steady state}$ ) <sup>a</sup>	MOSFET		72	90	
	Schottky		85	100	

#### Notes

a. Surface Mounted on FR4 Board.

b.  $t \leq 10$  sec.

For SPICE model information via the Worldwide Web: <http://www.vishay.com/www/product/spice.htm>

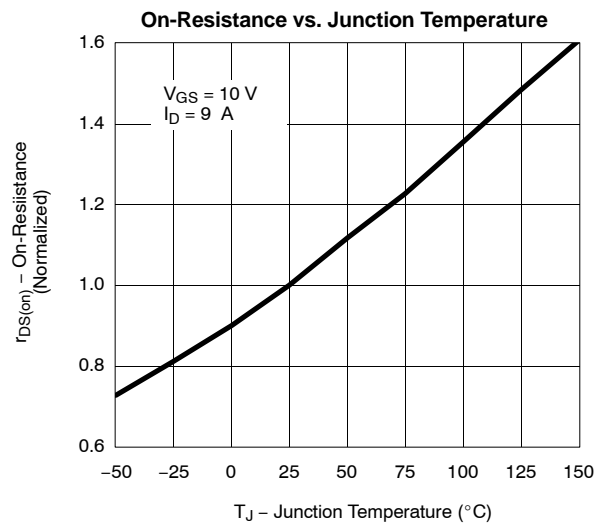
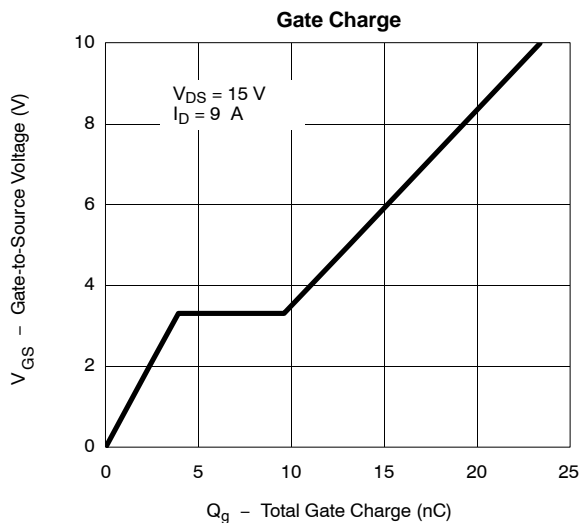
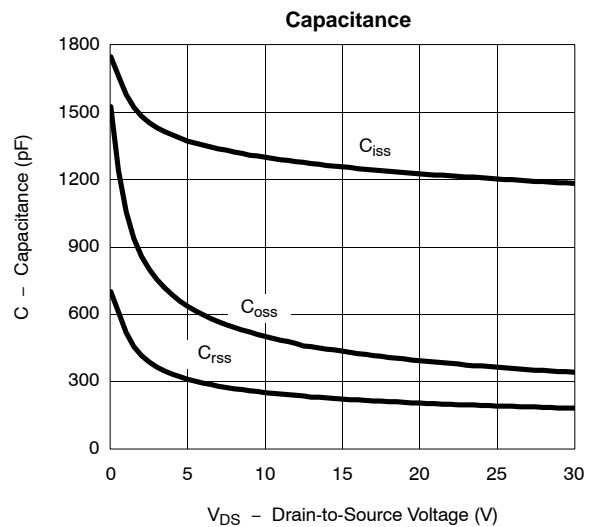
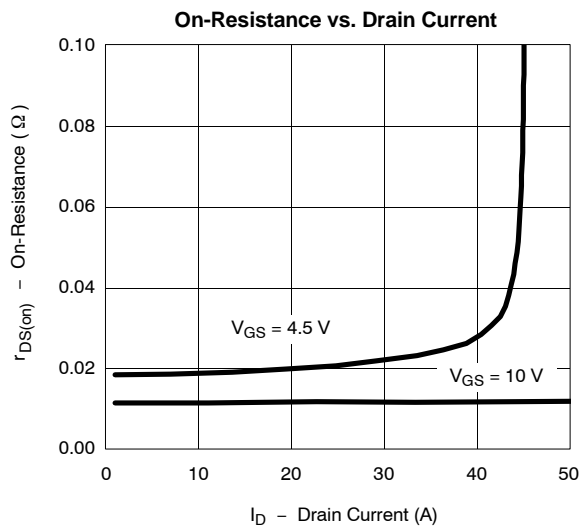
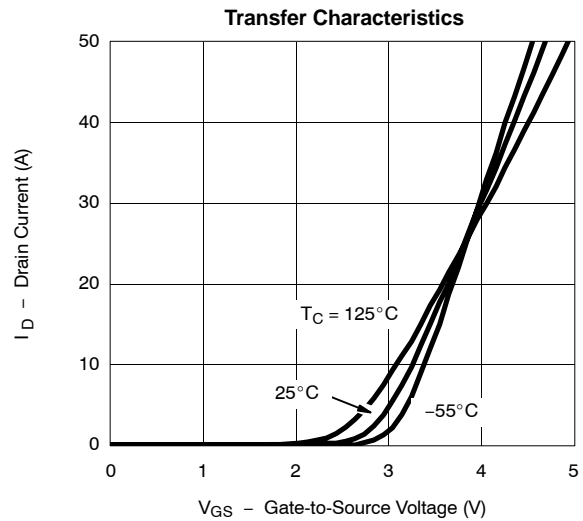
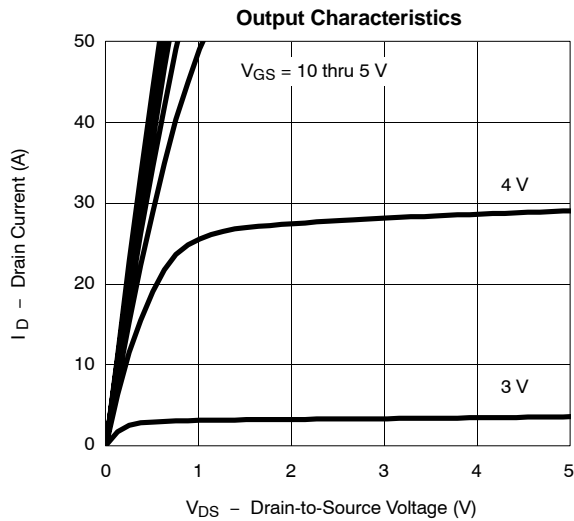
MOSFET + SCHOTTKY SPECIFICATIONS (T <sub>J</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1		3	V
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current (MOSFET + Schottky)	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V		0.004	0.100	mA
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 100°C		0.7	10	
		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125°C		3.0	20	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> ≥ 5 V, V <sub>GS</sub> = 10 V	20			A
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 9 A		0.012	0.018	Ω
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 7.3 A		0.019	0.028	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 9 A		23		S
Schottky Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 1.0 A, V <sub>GS</sub> = 0 V		0.45	0.50	V
		I <sub>S</sub> = 1.0 A, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125°C		0.33	0.42	
Dynamic <sup>b</sup>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 5 V, I <sub>D</sub> = 9 A		13	24	nC
Gate-Source Charge	Q <sub>gs</sub>			4		
Gate-Drain Charge	Q <sub>gd</sub>			5.7		
Gate Resistance	R <sub>g</sub>		0.2		2.4	Ω
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, R <sub>L</sub> = 15 Ω I <sub>D</sub> ≅ 1 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 6 Ω		16	25	ns
Rise Time	t <sub>r</sub>			10	20	
Turn-Off Delay Time	t <sub>d(off)</sub>			35	50	
Fall Time	t <sub>f</sub>			13	20	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.0 A, di/dt = 100 A/μs		35	70	

## Notes

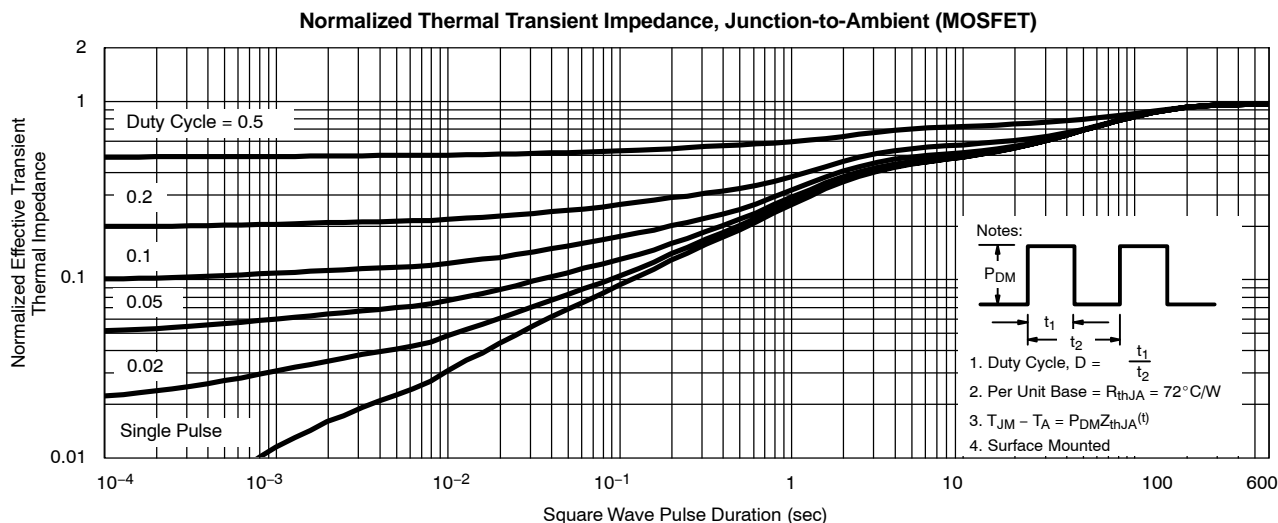
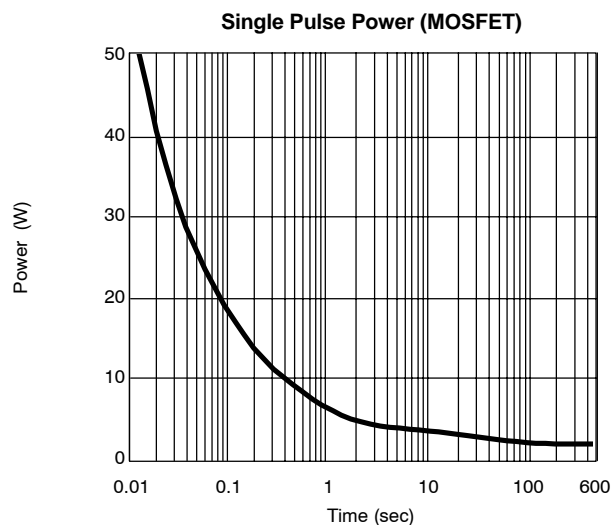
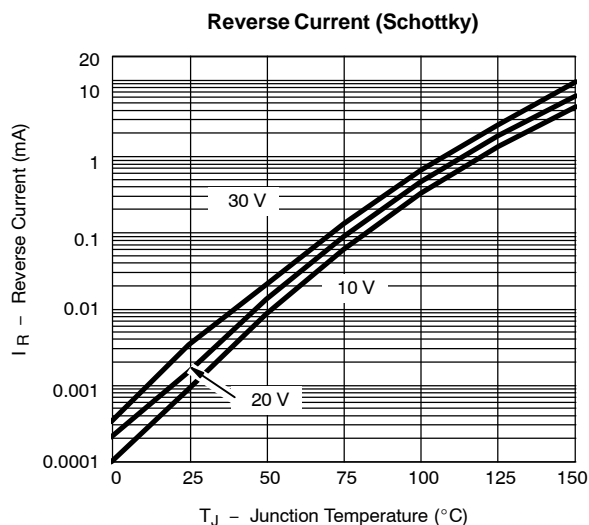
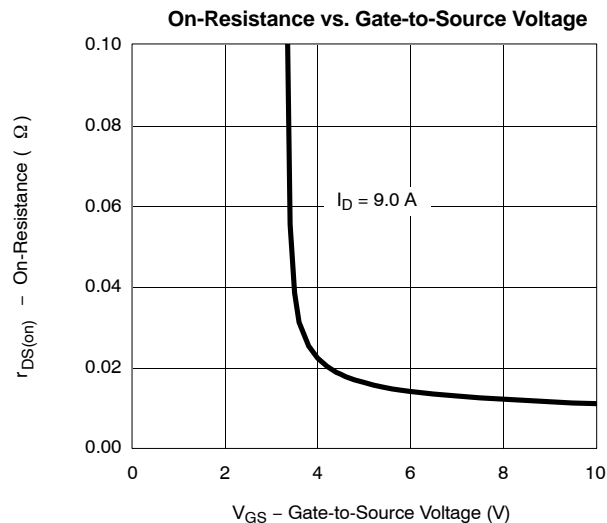
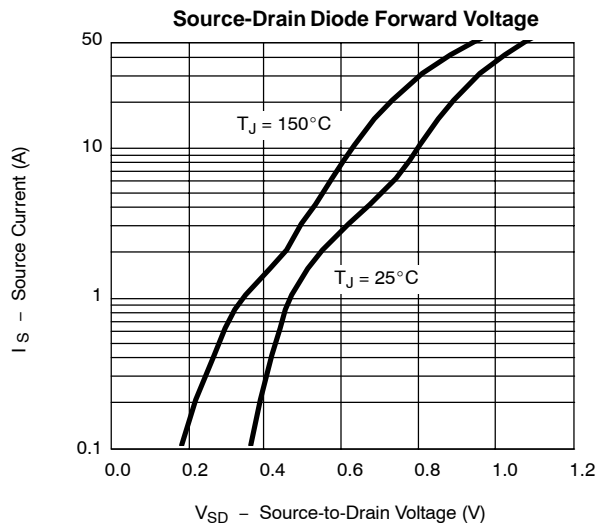
- a. Pulse test; pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.



**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**

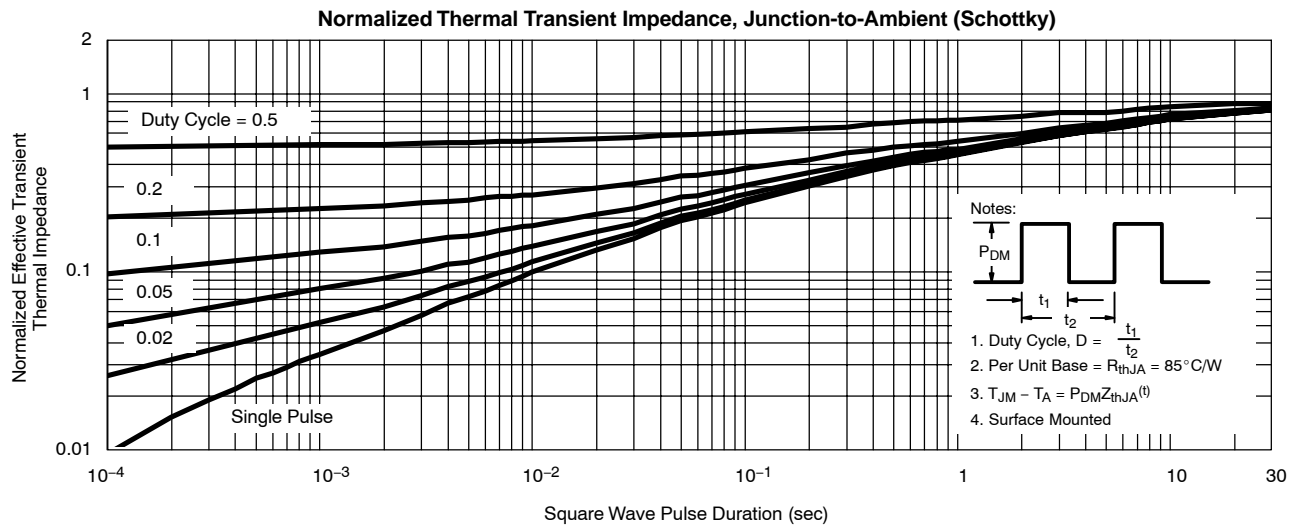


**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**





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